

	Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 12406-021001	Application No. 09/913,394
	Information Disclosure Statement by Applicant (Use several sheets if necessary)			Applicant Osram Opto Semiconductors GmbH & Co. OHG
				Filing Date August 13, 2001
	(37 CFR 1.53(b))			

U.S. Patent Documents

Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
VAMS	AA	6,023,077	02/08/2000	Iyechika et al.			
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
VAMS	AL	DE 19648955	05/28/1997	Germany				
	AM							
	AN							
	AO							
	AP							

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
VAMS	AQ	Sergey Yu. Karpov et al., "A Quantitative Model of Surface...", Materials Research Society, Vol. 618, 2000, pgs. 185-191.
VAMS	AR	Jean-Michel Gérard, "Growth of InGaAs/GaAs heterostructures with abrupt interfaces on the monolayer scale", Journal of Crystal Growth, Vol. 150, 1995, pgs. 467-472.
	AS	
	AT	

Examiner Signature <i>VAMS A. Mandalay</i>	Date Considered 9-2-04
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	